MC100EL29

5 V ECL Dual Differential Data and Clock D Flip-Flop With Set and Reset

ON Semiconductor®

SOIC−20 WB
WB SUFFIX
CASE 751D−05

Description

The MC100EL29 is a dual master-slave flip flop. The device features fully differential Data and Clock inputs as well as outputs. Data enters the master latch when the clock is LOW and transfers to the slave upon a positive transition on the clock input.

The V_{BB} pin, an internally generated voltage supply, is available to this device only. For single-ended input conditions, the unused differential input is connected to V_{BB} as a switching reference voltage. V_{BB} may also rebias AC coupled inputs. When used, decouple V_{BB} and V_{CC} via a 0.01 μF capacitor and limit current sourcing or sinking to 0.5 mA. When not used, V_{BB} should be left open.

The differential inputs have special circuitry which ensures device stability under open input conditions. When both differential inputs are left open the D input will pull down to V_{EE} and the $\overline{D}$ input will bias around $V_{CC}/2$. The outputs will go to a defined state, however the state will be random based on how the flip flop powers up.

Both flip flops feature asynchronous, overriding Set and Reset inputs. Note that the Set and Reset inputs cannot both be HIGH simultaneously.

The 100 Series Contains Temperature Compensation.

Features

- 1100 MHz Flip-Flop Toggle Frequency
- 580 ps Propagation Delays
- Q Output will Default LOW with Inputs Open or at V_{EE}
- PECL Mode Operating Range: $V_{CC} = 4.2$ V to 5.7 V
  with $V_{EE} = 0$ V
- NECL Mode Operating Range: $V_{CC} = 0$ V
  with $V_{EE} = -4.2$ V to −5.7 V
- Internal Input Pulldown Resistors on D(s), CLK(s), S(s), and R(s).
- ESD Protection:
  - \> 2 kV Human Body Model
  - \> 100 V Machine Model
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity: Level 3 (Pb-Free)
  (For Additional Information, see Application Note AND8003/D)
- Flammability Rating: UL 94 V−0 @ 1.125 in,
  Oxygen Index: 28 to 34
- Transistor Count = 313 Devices
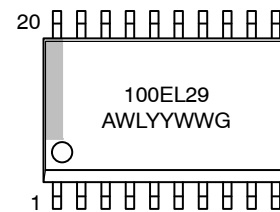- This Device is Pb-Free, Halogen Free and is RoHS Compliant

MARKING DIAGRAM*

20 [ㅂㅂㅂㅂㅂㅂㅂㅂㅂㅂ]

100EL29
AWLYYWWG

1 [ㅂㅂㅂㅂㅂㅂㅂㅂㅂㅂ]
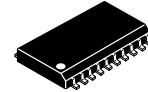
A	= Assembly Location
WL	= Wafer Lot
YY	= Year
WW	= Work Week
G	= Pb-Free Package

*For additional marking information, refer to Application Note AND8002/D.

ORDERING INFORMATION

Device	Package	Shipping
MC100EL29DWG	SOIC−20 WB (Pb-Free)	38 Units/Tube
MC100EL29DWR2G	SOIC−20 WB (Pb-Free)	1000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MC100EL29
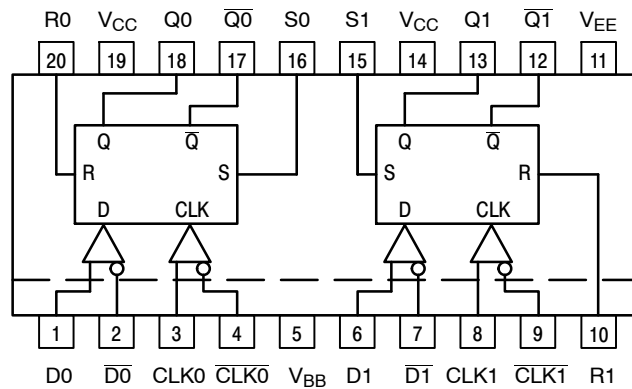
* All V_{CC} pins are tied together on the die.

Warning: All V_{CC} and V_{EE} pins must be externally connected
to Power Supply to guarantee proper operation.

Figure 1. Logic Diagram and Pinout: 20-Lead SOIC (Top View)

Table 1. PIN DESCRIPTION

PIN	FUNCTION
D0, $\overline{D0}$; D1, $\overline{D1}$	ECL Differential Data Inputs
R0–R1	ECL Reset Inputs
CLK0, $\overline{CLK0}$; CLK1, $\overline{CLK1}$	ECL Differential Clock Inputs
S0–S1	ECL Set Inputs
Q0, $\overline{Q0}$; Q1, $\overline{Q1}$	ECL Differential Data Outputs
V_{BB}	Reference Voltage Output
V_{CC}	Positive Supply
V_{EE}	Negative Supply

Table 2. TRUTH TABLE

R*	S*	D*	CLK*	Q	$\overline{Q}$
L	L	L	Z	L	H
L	L	H	Z	H	L
H	L	X	X	L	H
L	H	X	X	H	L
H	H	X	X	Undef	Undef

Z = LOW to HIGH Transition
* Pins will default LOW when left open.

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V_{CC}	PECL Mode Power Supply	V_{EE} = 0 V		8	V
V_{EE}	NECL Mode Power Supply	V_{CC} = 0 V		−8	V
V_I	PECL Mode Input Voltage NECL Mode Input Voltage	V_{EE} = 0 V V_{CC} = 0 V	$V_I \leq V_{CC}$ $V_I \geq V_{EE}$	6 −6	V V
I_{out}	Output Current	Continuous Surge		50 100	mA mA
I_{BB}	V_{BB} Sink/Source			±0.5	mA
T_A	Operating Temperature Range			−40 to +85	°C
T_{stg}	Storage Temperature Range			−65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	SOIC−20 WB SOIC−20 WB	90 60	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	SOIC−20 WB	30 to 35	°C/W
T_{sol}	Wave Solder (Pb-Free)			265	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 4. 100EL SERIES PECL DC CHARACTERISTICS (V_{CC} = 5.0 V; V_{EE} = 0.0 V (Note 1))

Symbol	Characteristic	−40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		130	156		130	156		130	156	mA
I_{EE}	Power Supply Current		35	50		35	50		35	50	mA
V_{OH}	Output HIGH Voltage (Note 2)	3915	3995	4120	3975	4045	4120	3975	4050	4120	mV
V_{OL}	Output LOW Voltage (Note 2)	3170	3305	3445	3190	3295	3380	3190	3295	3380	mV
V_{IH}	Input HIGH Voltage (Single-Ended)	3835		4120	3835		4120	3835		4120	mV
V_{IL}	Input LOW Voltage (Single-Ended)	3190		3525	3190		3525	3190		3525	mV
V_{BB}	Output Voltage Reference	3.62		3.74	3.62		3.74	3.62		3.74	V
V_{IHCMR}	Common Mode Range (Differential Configuration) (Note 3) V_{PP} < 500 mV V_{PP} ≥ 500 mV	1.3 1.5		4.6 4.6	1.2 1.4		4.6 4.6	1.2 1.4		4.6 4.6	V
I_{IH}	Input HIGH Current			150			150			150	µA
I_{IL}	Input LOW Current	0.5			0.5			0.5			µA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.8 V / −0.5 V.
2. Outputs are terminated through a 50 Ω resistor to V_{CC} − 2.0 V.
3. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP} min and 1 V.

Table 5. 100E SERIES NECL DC CHARACTERISTICS (V_{CC} = 0.0 V; V_{EE} = −5.0 V (Note 1))

Symbol	Characteristic	−40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		35	50		35	50		35	50	mA
V_{OH}	Output HIGH Voltage (Note 2)	−1085	−1005	−880	−1025	−955	−880	−1025	−955	−880	mV
V_{OL}	Output LOW Voltage (Note 2)	−1830	−1695	−1555	−1810	−1705	−1620	−1810	−1705	−1620	mV
V_{IH}	Input HIGH Voltage (Single-Ended)	−1165		−880	−1165		−880	−1165		−880	mV
V_{IL}	Input LOW Voltage (Single-Ended)	−1810		−1475	−1810		−1475	−1810		−1475	mV
V_{BB}	Output Voltage Reference	−1.38		−1.26	−1.38		−1.26	−1.38		−1.26	V
V_{IHCMR}	Common Mode Range (Differential Configuration) (Note 3) V_{PP} < 500 mV V_{PP} ≥ 500 mV	−3.7 −3.5		−0.4 −0.4	−3.8 −3.6		−0.4 −0.4	−3.8 −3.6		−0.4 −0.4	V
I_{IH}	Input HIGH Current			150			150			150	µA
I_{IL}	Input LOW Current	0.5			0.5			0.5			µA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.8 V / −0.5 V.
2. Outputs are terminated through a 50 Ω resistor to V_{CC} − 2.0 V.
3. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP} min and 1 V.

Table 6. AC CHARACTERISTICS (V_{CC} = 5.0 V; V_{EE} = 0.0 V or V_{CC} = 0.0 V; V_{EE} = −5.0 V (Note 1))

Symbol	Characteristic	−40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
fmax	Maximum Toggle Frequency		TBD			TBD			TBD		GHz
t_{PLH} t_{PHL}	Propagation Delay CLK to Output S, R	480 480		680 700	500 500		700 720	520 520		720 740	ps
t_S t_H	Setup Time Hold Time	0 100			0 100			0 100			ps
t_{RR}	Set/Reset Recovery	100			100			100			ps
t_{PW}	Minimum Pulse Width CLK, Set, Reset	400			400			400			ps
t_{JITTER}	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
V_{PP}	Input Swing (Note 2)	150		1000	150		1000	150		1000	mV
t_r t_f	Output Rise/Fall Times Q (20%−80%)	280		550	280		550	280		550	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. V_{EE} can vary vary +0.8 V / −0.5 V.
2. V_{PP} (min) is minimum input swing for which AC parameters guaranteed. The device has a DC gain of $\approx$40.
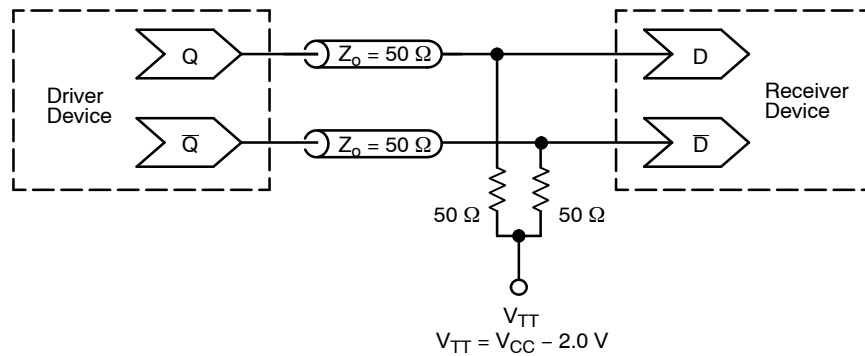
Figure 2. Typical Termination for Output Driver and Device Evaluation
(See Application Note AND8020/D – Termination of ECL Logic Devices)

Resource Reference of Application Notes

AN1405/D   – ECL Clock Distribution Techniques

AN1406/D   – Designing with PECL (ECL at +5.0 V)

AN1503/D   – ECLinPS™ I/O SPiCE Modeling Kit

AN1504/D   – Metastability and the ECLinPS Family

AN1568/D   – Interfacing Between LVDS and ECL

AN1672/D   – The ECL Translator Guide

AND8001/D   – Odd Number Counters Design

AND8002/D   – Marking and Date Codes

AND8020/D   – Termination of ECL Logic Devices

AND8066/D   – Interfacing with ECLinPS

**AND8090**/D   – AC Characteristics of ECL Devices

PACKAGE DIMENSIONS

SOIC−20 WB
DW SUFFIX
CASE 751D−05
ISSUE H
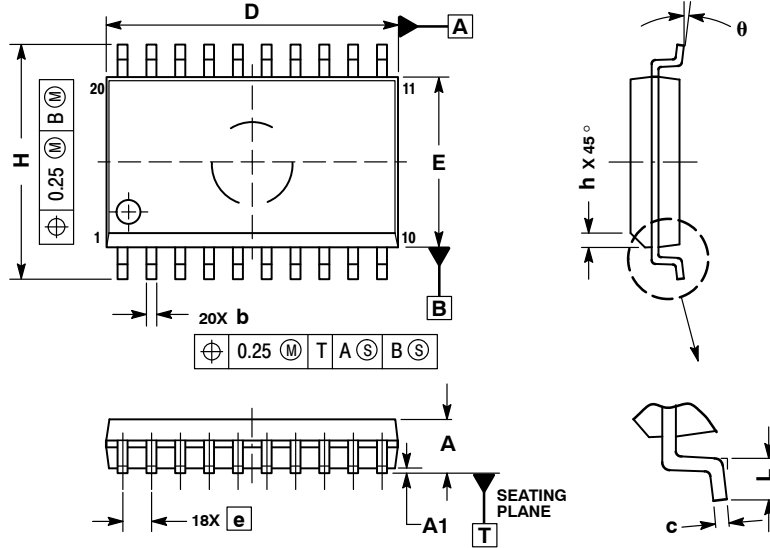
NOTES:
1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
b	0.35	0.49
c	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0 °	7 °

RECOMMENDED
SOLDERING FOOTPRINT*
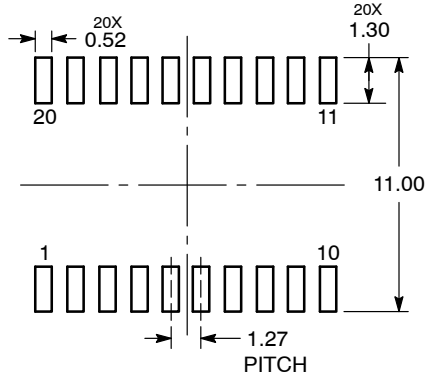
DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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